

RoHS MLA Automotive Varistor Series



Size Table

Metric	EIA
1608	0603
2012	0805
3216	1206
3225	1210

Applications

- Suppression of inductive switching or other transient events such as EFT and surge voltage at the circuit board level
- ESD protection for IEC 61000-4-2, MIL-STD-883c method 3015.7, and other industry specifications
- Provides on-board transient voltage protection for ICS and transistors
- Used to help achieve electromagnetic compliance of end products
- Replace larger surface mount TVS Zeners in many applications

Description

The MLA Automotive Series of transient voltage surge suppression devices is based on the Littelfuse Multilayer fabrication technology. These components are designed to suppress a variety of transient events, including those specified in IEC 61000-4-2 or other standards used for Electromagnetic Compliance (EMC). The MLA Automotive Series is typically applied to protect integrated circuits and other components at the circuit board level.

The wide operating voltage and energy range make the MLA Automotive Series suitable for numerous applications on power supply, control and signal lines.

The MLA Automotive Series is manufactured from semiconducting ceramics, and is supplied in a leadless, surface mount package. The MLA Automotive Series is compatible with modern reflow and wave soldering procedures.

It can operate over a wider temperature range than Zener diodes, and has a much smaller footprint than plastic-housed components.

Features

- AEC - Q200 compliant
- RoHS compliant
- Leadless 0603, 0805, 1206 and 1210 chip sizes
- Multilayer ceramic construction technology
- -55°C to +125°C operating temp. range
- Operating voltage range $V_{MDC} = 3.5V$ to 48V
- Rated for surge current (8 x 20µs)
- Rated for energy (10 x 1000µs)
- Inherent bi-directional clamping
- No plastic or epoxy packaging assures better than UL94V-0 flammability rating
- Standard low capacitance types available

Absolute Maximum Ratings

For ratings of individual members of a series, see device ratings and specifications table.

Continuous	MLA Auto Series	Units
Steady State Applied Voltage:		
DC Voltage Range (V_{MDC})	3.5 to 48	V
AC Voltage Range ($V_{MIA(RMS)}$)	2.5 to 40	V
Transient:		
Non-Repetitive Surge Current, 8/20µs Waveform, (I_{TM})	up to 500	A
Non-Repetitive Surge Energy, 10/1000µs Waveform, (W_{TM})	0.1 to 2.5	J
Operating Ambient Temperature Range (T_A)	-55 to +125	°C
Storage Temperature Range (T_{STG})	-55 to +150	°C
Temperature Coefficient (αV) of Clamping Voltage (V_C) at Specified Test Current	<0.01	%/°C

Device Ratings and Specifications

Part Number	Maximum Ratings (125° C)					Specifications (25°C)		
	Maximum Continuous Working Voltage		Maximum Non-repetitive Surge Current (8/20 μ s)	Maximum Non-repetitive Surge Energy (10/1000 μ s)	Maximum Clamping Voltage at 1A (or as Noted) (8/20 μ s)	Nominal Voltage at 1mA DC Test Current		Typical Capacitance at f = 1MHz
	V _{M(DC)}	V _{M(AC)}	I _{TM}	W _{TM}	V _C	V _{N(DC) Min}	V _{N(DC) Max}	C
	(V)	(V)	(A)	(J)	(V)	(V)	(V)	(pF)
V3.5MLA0603NHAUTO	3.5	2.5	30	0.100	13.0	3.7	7.0	1270
V3.5MLA0805NHAUTO	3.5	2.5	120	0.300	13.0	3.7	7.0	2530
V3.5MLA0805LNHAUTO	3.5	2.5	40	0.100	13.0	3.7	7.0	1380
V3.5MLA1206NHAUTO	3.5	2.5	100	0.300	13.0	3.7	7.0	6000
V5.5MLA0603NHAUTO	5.5	4.0	30	0.100	17.5	7.1	9.3	500
V5.5MLA0805NHAUTO	5.5	4.0	120	0.300	17.5	7.1	9.3	1840
V5.5MLA0805LNHAUTO	5.5	4.0	40	0.100	17.5	7.1	9.3	400
V5.5MLA1206NHAUTO	5.5	4.0	150	0.400	17.5	7.1	9.3	3500
V9MLA0603NHAUTO	9.0	6.5	30	0.100	25.5	11.0	16.0	490
V9MLA0805LNHAUTO	9.0	6.5	40	0.100	25.5	11.0	16.0	520
V12MLA0805LNHAUTO	12.0	9.0	40	0.100	29.0	14.0	18.5	410
V14MLA0603NHAUTO	14.0	10.0	30	0.100	34.5	15.9	21.5	180
V14MLA0805NHAUTO	14.0	10.0	120	0.300	32.0	15.9	20.3	560
V14MLA0805LNHAUTO	14.0	10.0	40	0.100	32.0	15.9	20.3	320
V14MLA1206NHAUTO	14.0	10.0	150	0.400	32.0	15.9	20.3	1400
V18MLA0603NHAUTO	18.0	14.0	30	0.100	50.0	22.0	28.0	120
V18MLA0805NHAUTO	18.0	14.0	120	0.300	44.0	22.0	28.0	520
V18MLA0805LNHAUTO	18.0	14.0	40	0.100	44.0	22.0	28.0	290
V18MLA1206NHAUTO	18.0	14.0	150	0.400	44.0	22.0	28.0	1270
V18MLA1210NHAUTO	18.0	14.0	500	2.500	44.0 at 2.5	22.0	28.0	1440
V26MLA0603NHAUTO	26.0	20.0	30	0.100	60.0	31.0	38.0	110
V26MLA0805NHAUTO	26.0	20.0	100	0.300	60.0	29.5	38.5	220
V26MLA0805LNHAUTO	26.0	20.0	40	0.100	60.0	29.5	38.5	140
V26MLA1206NHAUTO	26.0	20.0	150	0.600	60.0	29.5	38.5	600
V26MLA1210NHAUTO	26.0	20.0	300	1.200	60.0 at 2.5	29.5	38.5	1040
V30MLA0603NHAUTO	30.0	25.0	30	0.100	74.0	37.0	46.0	90
V30MLA0805LNHAUTO	30.0	25.0	30	0.100	72.0	37.0	46.0	90
V30MLA1210NHAUTO	30.0	25.0	280	1.200	68.0 at 2.5	35.0	43.0	1820
V30MLA1210LNHAUTO	30.0	25.0	220	0.900	68.0 at 2.5	35.0	43.0	1760
V33MLA1206NHAUTO	33.0	26.0	180	0.800	75.0	38.0	49.0	500
V42MLA1206NHAUTO	42.0	30.0	180	0.800	92.0	46.0	60.0	425
V48MLA1210NHAUTO	48.0	40.0	250	1.200	105.0 at 2.5	54.5	66.5	520
V48MLA1210LNHAUTO	48.0	40.0	220	0.900	105.0 at 2.5	54.5	66.5	500

NOTES:

- 'L' suffix is a low capacitance and energy version; Contact your Littelfuse sales representative for custom capacitance requirements
- Typical leakage at 25°C < 25 μ A, maximum leakage 100 μ A at V_{M(DC)}
- Average power dissipation of transients for 0603, 0805, 1206 and 1210 sizes not to exceed 0.05W, 0.1W, 0.1W and 0.15W respectively

Peak Current and Energy Derating Curve

When transients occur in rapid succession, the average power dissipation is the energy (watt-seconds) per pulse times the number of pulses per second. The power so developed must be within the specifications shown on the Device Ratings and Specifications Table for the specific device. For applications exceeding 125°C ambient temperature, the peak surge current and energy ratings must be derated as shown below.

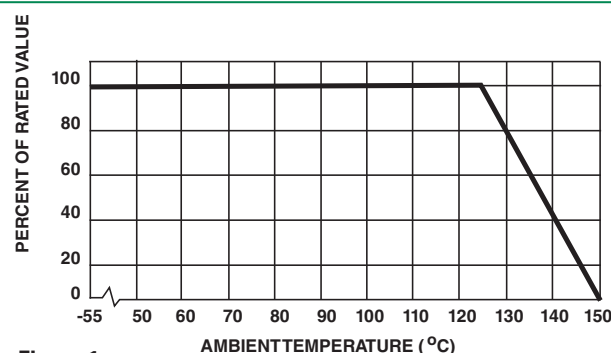


Figure 1

Peak Pulse Current Test Waveform for Clamping Voltage

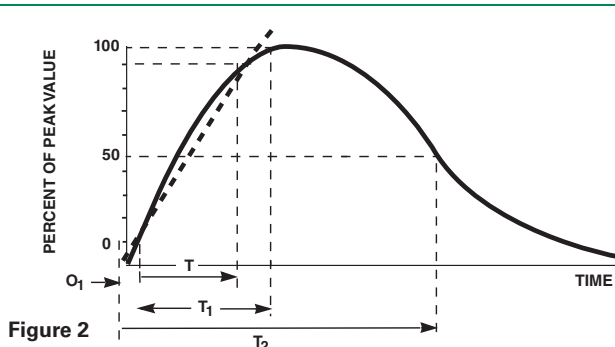


Figure 2

O_1 = Virtual Origin of Wave
 T = Time from 10% to 90% of Peak
 T_1 = Rise Time = $1.25 \times T$
 T_2 = Decay Time

Example - For an 8/20 μs Current Waveform:

$8\mu s = T_1$ = Rise Time

$20\mu s = T_2$ = Decay Time

Limit V-I Characteristic for V3.5MLA0603 to V30MLA0603

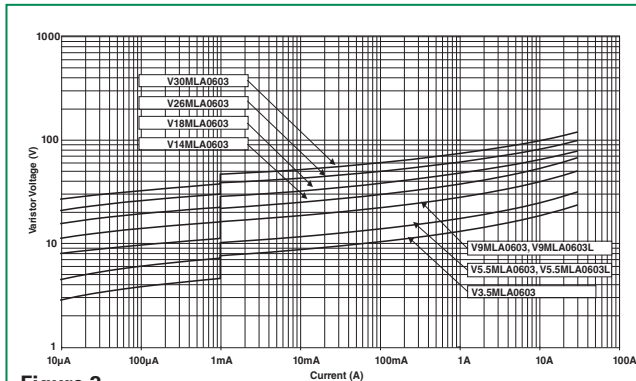


Figure 3

Limit V-I Characteristic for V3.5MLA0805L to V30MLA0805L

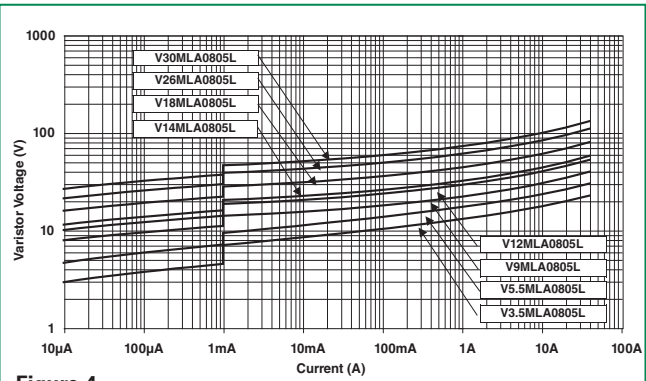


Figure 4

Limit V-I Characteristic for V3.5MLA0805 to V26MLA0805

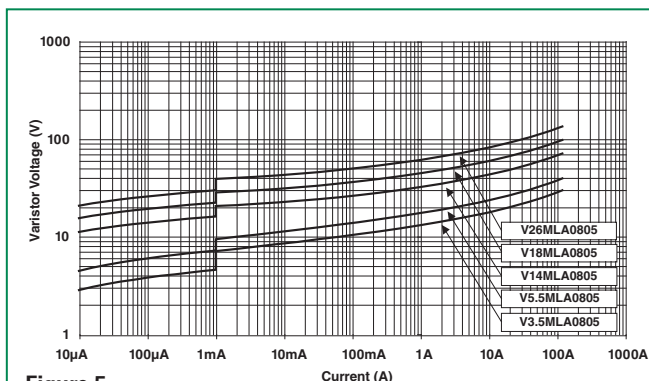


Figure 5

Limit V-I Characteristic for V3.5MLA1206 to V42MLA1206

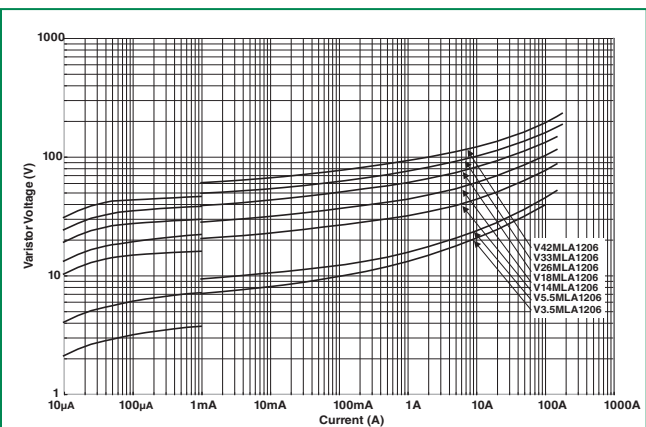


Figure 7

Limit V-I Characteristic for V18MLA1210 to V48MLA1210

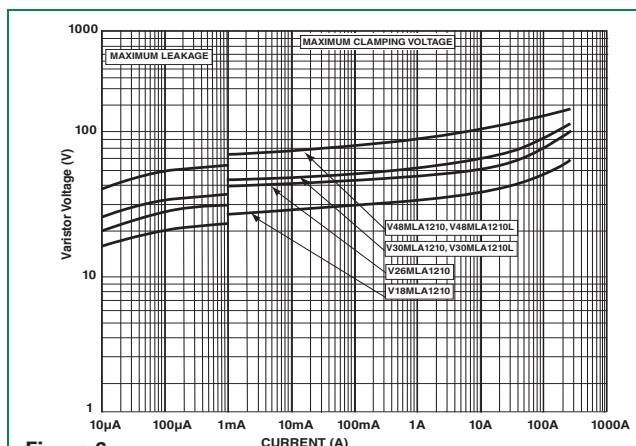
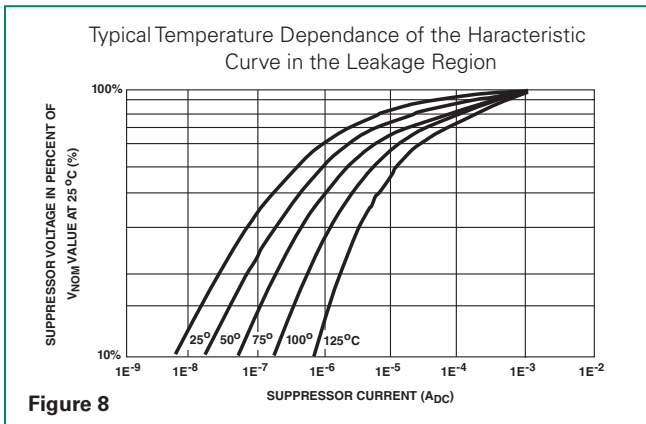


Figure 6

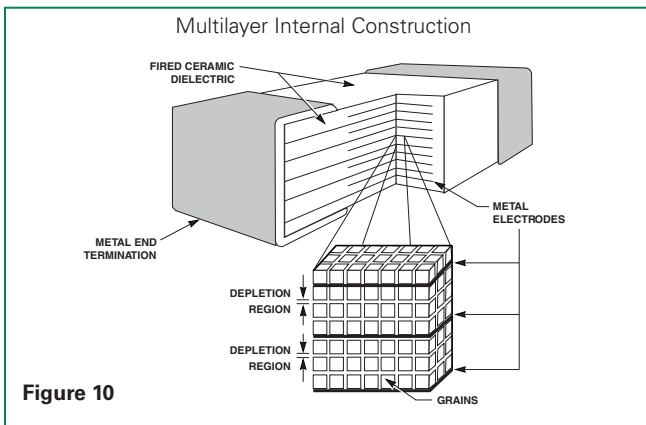
Device Characteristics

At low current levels, the V-I curve of the multilayer transient voltage suppressor approaches a linear (ohmic) relationship and shows a temperature dependent effect. At or below the maximum working voltage, the suppressor is in a high resistance mode (approaching $10^6\Omega$ at its maximum rated working voltage). Leakage currents at maximum rated voltage are below $100\mu A$, typically $25\mu A$.

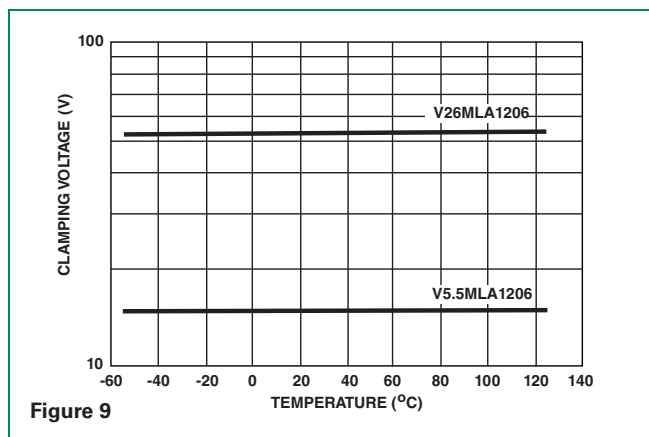


Speed of Response

The Multilayer Suppressor is a leadless device. Its response time is not limited by the parasitic lead inductances found in other surface mount packages. The response time of the $Z_{N}O$ dielectric material is less than 1ns and the MLA Automotive Series can clamp very fast dV/dT events such as ESD. Additionally, in "real world" applications, the associated circuit wiring is often the greatest factor effecting speed of response. Therefore, transient suppressor placement within a circuit can be considered important in certain instances.



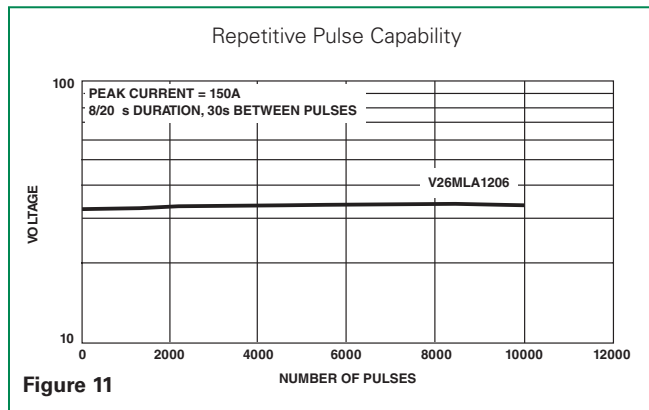
Clamping Voltage Over Temperature (V_c at 10A)



Energy Absorption/Peak Current Capability

Energy dissipated within the MLA Automotive Series is calculated by multiplying the clamping voltage, transient current and transient duration. An important advantage of the multilayer is its interdigitated electrode construction within the mass of dielectric material. This results in excellent current distribution and the peak temperature per energy absorbed is very low. The matrix of semiconducting grains combine to absorb and distribute transient energy (heat) (see Speed of Response). This dramatically reduces peak temperature; thermal stresses and enhances device reliability.

As a measure of the device capability in energy and peak current handling, the V26MLA1206 part was tested with multiple pulses at its peak current rating (150A, 8/20 μs). At the end of the test, 10,000 pulses later, the device voltage characteristics are still well within specification.



Lead (Pb) Soldering Recommendations

The principal techniques used for the soldering of components in surface mount technology are IR Re-flow and Wave soldering. Typical profiles are shown on the right.

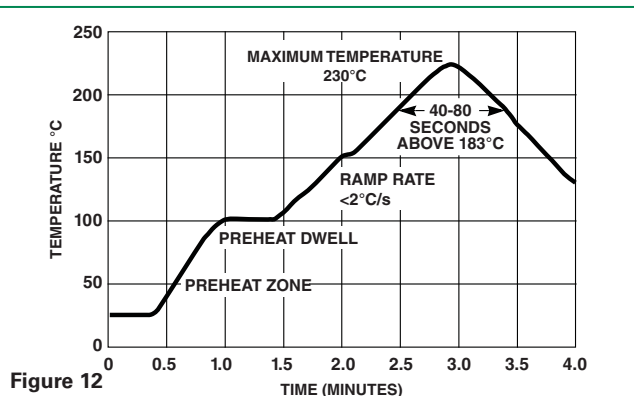
The recommended solder for the MLA Automotive Series suppressor is a 62/36/2 (Sn/Pb/Ag), 60/40 (Sn/Pb) or 63/37 (Sn/Pb). Littelfuse also recommends an RMA solder flux.

Wave soldering is the most strenuous of the processes. To avoid the possibility of generating stresses due to thermal shock, a preheat stage in the soldering process is recommended, and the peak temperature of the solder process should be rigidly controlled.

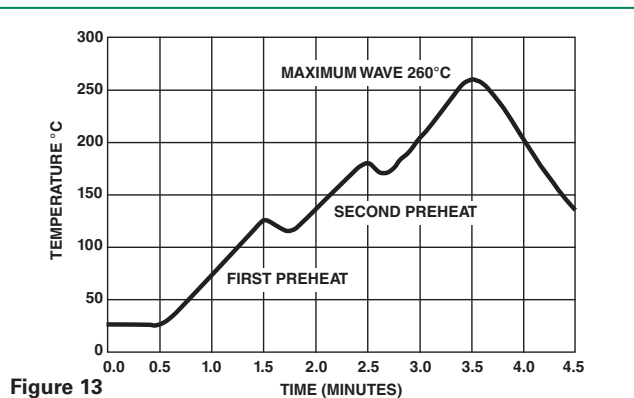
When using a reflow process, care should be taken to ensure that the MLA Automotive Series chip is not subjected to a thermal gradient steeper than 4 degrees per second; the ideal gradient being 2 degrees per second. During the soldering process, preheating to within 100 degrees of the solder's peak temperature is essential to minimize thermal shock.

Once the soldering process has been completed, it is still necessary to ensure that any further thermal shocks are avoided. One possible cause of thermal shock is hot printed circuit boards being removed from the solder process and subjected to cleaning solvents at room temperature. The boards must be allowed to cool gradually to less than 50° C before cleaning.

Reflow Solder Profile



Wave Solder Profile



Lead-free (Pb-free) Soldering Recommendations

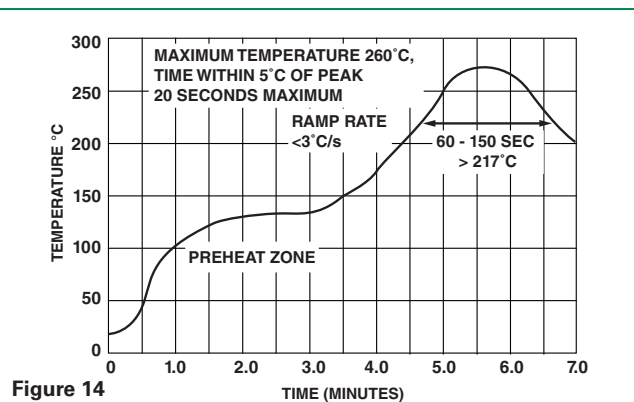
Littelfuse offers the Nickel Barrier Termination option (see "N" suffix in Part Numbering System for ordering) for the optimum Lead-free solder performance, consisting of a Matte Tin outer surface plated on Nickel underlayer, plated on Silver base metal.

The preferred solder is 96.5/3.0/0.5 (SnAgCu) with an RMA flux, but there is a wide selection of pastes and fluxes available with which the Nickel Barrier parts should be compatible.

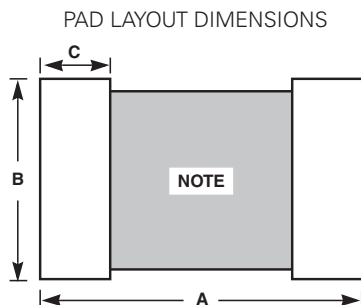
The reflow profile must be constrained by the maximums in the Lead-free Reflow Profile. For Lead-free wave soldering, the Wave Solder Profile still applies.

Note: the Lead-free paste, flux and profile were used for evaluation purposes by Littelfuse, based upon industry standards and practices. There are multiple choices of all three available, it is advised that the customer explores the optimum combination for their process as processes vary considerably from site to site.

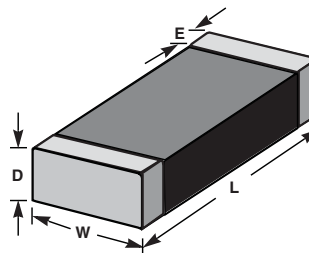
Lead-free Re-flow Solder Profile



Product Dimensions (mm)



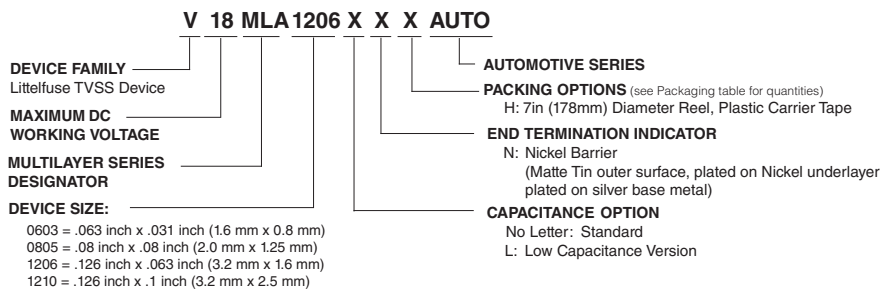
CHIP LAYOUT DIMENSIONS



NOTE : Avoid metal runs in this area, parts not recommended for use in applications using Silver (Ag) epoxy paste.

Dimension	1210 Size		1206 Size		0805 Size		0603 Size	
	IN	MM	IN	MM	IN	MM	IN	MM
A	0.160	4.06	0.160	4.06	0.120	3.05	0.100	2.54
B	0.100	2.54	0.065	1.65	0.050	1.27	0.030	0.76
C	0.040	1.02	0.040	1.02	0.040	1.02	0.035	0.89
D (max.)	0.113	2.87	0.071	1.80	0.043	1.10	0.040	1.00
E	0.020 -/+0.010	0.50 -/+0.25	0.020 -/+0.010	0.50 -/+0.25	0.020 +/- 0.010	0.50 +/- 0.25	0.015 -/+0.008	0.4 -/+0.20
L	0.125 -/+0.012	3.20 -/+0.30	0.125 -/+0.012	3.20 -/+0.30	0.079 -/+0.008	2.01 -/+0.20	0.063 -/+0.006	1.6 -/+0.15
W	0.100 -/+0.012	2.54 -/+0.30	0.060 -/+0.011	1.60 -/+0.28	0.049 -/+0.008	1.25 -/+0.20	0.032 -/+0.060	0.8 -/+0.15

Part Numbering System

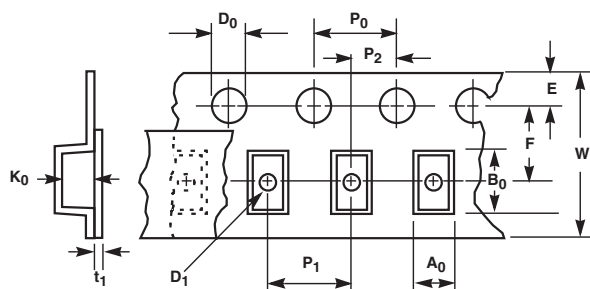


Packaging*

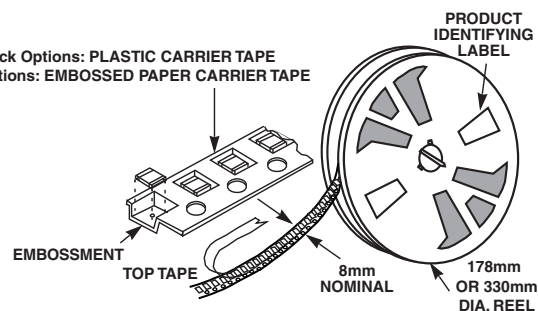
Device Size	Quantity
	7" Inch Reel ("H" Option)
1210	2,000
1206	2,500
0805	2,500
0603	2,500

*(Packaging) It is recommended that parts be kept in the sealed bag provided and that parts be used as soon as possible when removed from bags.

Tape and Reel Specifications



For T and H Pack Options: PLASTIC CARRIER TAPE
For R Pack Options: EMBOSSED PAPER CARRIER TAPE



Symbol	Description	Dimensions in Millimeters
		0603, 0805, 1206 & 1210 Sizes
A_0	Width of Cavity	Dependent on Chip Size to Minimize Rotation.
B_0	Length of Cavity	Dependent on Chip Size to Minimize Rotation.
K_0	Depth of Cavity	Dependent on Chip Size to Minimize Rotation.
W	Width of Tape	8 $\pm$ 0.3
F	Distance Between Drive Hole Centers and Cavity Centers	3.5 $\pm$ 0.05
E	Distance Between Drive Hole Centers and Tape Edge	1.75 $\pm$ 0.1
P_1	Distance Between Cavity Centers	4 $\pm$ 0.1
P_2	Axial Drive Distance Between Drive Hole Centers & Cavity Centers	2 $\pm$ 0.1
P_0	Axial Drive Distance Between Drive Hole Centers	4 $\pm$ 0.1
D_0	Drive Hole Diameter	1.55 $\pm$ 0.05
D_1	Diameter of Cavity Piercing	1.05 $\pm$ 0.05
T_1	Top Tape Thickness	0.1 Max

NOTES:

- Conforms to EIA-481-1, Revision A
- Can be supplied to IEC publication 286-3

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9